DS05-11103-2E

MEMORY

Un-buffered

4 M \times 64 BIT SYNCHRONOUS DYNAMIC RAM DIMM

MB8504S064AC-100/-84/-67

168-pin, 2-clock, 2-bank, based on 2 M × 8 BIT SDRAMs with SPD

■ DESCRIPTION

The Fujitsu MB8504S064AC is a fully decoded, CMOS Synchronous Dynamic Random Access Memory (SDRAM) Module consisting of sixteen MB81117822A devices which organized as two banks of 2 M \times 8 bits and a 2K-bit serial EEPROM on a 168-pin glass-epoxy substrate.

The MB8504S064AC features a fully synchronous operation referenced to a positive edge clock whereby all operations are synchronized at a clock input which enables high performance and simple user interface coexistence.

The MB8504S064AC is optimized for those applications requiring high speed, high performance and large memory storage, and high density memory organizations.

This module is ideally suited for workstations, PCs, laser printers, and other applications where a simple interface is needed.

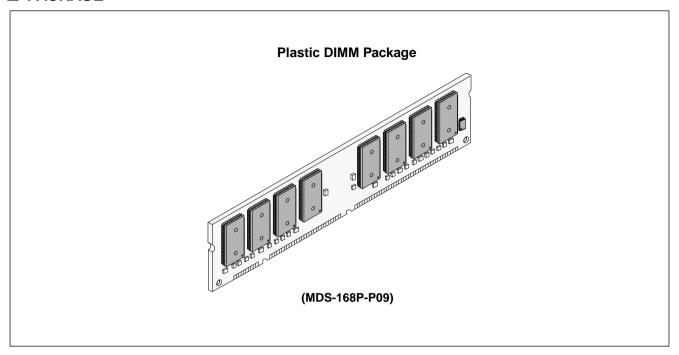
■ PRODUCT LINE & FEATURES

Para	ameter	MB8504S064AC-100	MB8504S064AC-84	MB8504S064AC-67		
Clock Frequency		100 MHz max.	100 MHz max. 84 MHz max.			
Burst Mode Cycle	Time	10 ns max. (CL = 3) 15 ns max. (CL = 2)	12 ns max. (CL = 3) 17 ns max. (CL = 2)	15 ns max. (CL = 3) 20 ns max. (CL = 2)		
RAS Access Time		54 ns max.	54 ns max. 56 ns max.			
CAS Access Time		24 ns max.	24 ns max. 26 ns max. 30 ns			
Output Valid from Clock		8.5 ns max. (CL = 3) 9 ns max. (CL = 2)	8.5 ns max. (CL = 3) 9 ns max. (CL = 2)	9 ns max. (CL = 3) 10 ns max. (CL = 2)		
Power	Burst Mode	4752 mW max.	4464 mW max.	4176 mW max.		
Dissipation	Power Down Mode	115.2 mW max.				

- Un-buffered 168-pin DIMM Socket Type (Lead pitch: 1.27 mm)
- Conformed to JEDEC Standard (2 CLK)
- Organization: 4,194,304 words × 64 bits
- Memory: MB81117822A (2 M×8, 2-bank)×16 pcs.
- 3.3 V ± 0.3 V Supply Voltage
- All input/output LVTTL compatible

- 2048 Refresh Cycle every 32.8 ms
- Auto and Self Refresh
- CKE Power Down Mode
- DQM Byte Masking (Read/Write)
- Serial Presence Detect (SPD) with Serial EEPROM
- Module size : 1.0" (height) \times 5.25" (length) \times 0.157" (thick)

■ PACKAGE

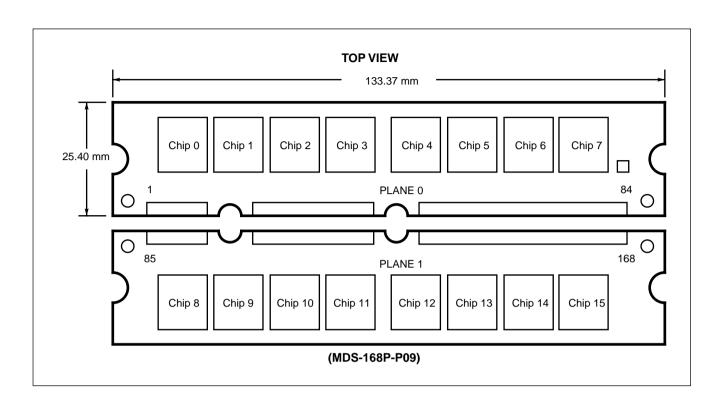


Package and Ordering Information

- 168-pad DIMM, order as MB8504S064AC-××DG (DG = Gold Pad)

■ PIN ASSIGNMENTS

Pin No.	Signal Name	Pin No.	Signal Name	Pin No.	Signal Name	Pin No.	Signal Name	Pin No.	Signal Name	Pin No.	Signal Name
1	Vss	29	DQMB ₁	57	DQ ₁₈	85	Vss	113	DQMB₅	141	DQ ₅₀
2	DQo	30	CS ₀	58	DQ ₁₉	86	DQ ₃₂	114	CS ₁	142	DQ ₅₁
3	DQ ₁	31	N.C.	59	Vcc	87	DQ ₃₃	115	RAS	143	Vcc
4	DQ ₂	32	Vss	60	DQ ₂₀	88	DQ ₃₄	116	Vss	144	DQ ₅₂
5	DQ₃	33	A ₀	61	N.C.	89	DQ ₃₅	117	A ₁	145	N.C.
6	Vcc	34	A ₂	62	N.C.	90	Vcc	118	Аз	146	N.C.
7	DQ ₄	35	A ₄	63	N.C.	91	DQ ₃₆	119	A 5	147	N.C.
8	DQ ₅	36	A 6	64	Vss	92	DQ ₃₇	120	A ₇	148	Vss
9	DQ ₆	37	A8	65	DQ ₂₁	93	DQ ₃₈	121	A 9	149	DQ ₅₃
10	DQ ₇	38	A ₁₀	66	DQ ₂₂	94	DQ ₃₉	122	A ₁₁	150	DQ ₅₄
11	DQ ₈	39	N.C.	67	DQ ₂₃	95	DQ ₄₀	123	N.C.	151	DQ ₅₅
12	Vss	40	Vcc	68	Vss	96	Vss	124	Vcc	152	Vss
13	DQ ₉	41	Vcc	69	DQ ₂₄	97	DQ ₄₁	125	CLK ₁	153	DQ ₅₆
14	DQ ₁₀	42	CLK ₀	70	DQ ₂₅	98	DQ ₄₂	126	N.C.	154	DQ ₅₇
15	DQ ₁₁	43	Vss	71	DQ ₂₆	99	DQ ₄₃	127	Vss	155	DQ ₅₈
16	DQ ₁₂	44	N.C.	72	DQ ₂₇	100	DQ ₄₄	128	CKE	156	DQ59
17	DQ ₁₃	45	$\overline{\text{CS}}_2$	73	Vcc	101	DQ ₄₅	129	CS ₃	157	Vcc
18	Vcc	46	DQMB ₂	74	DQ ₂₈	102	Vcc	130	DQMB ₆	158	DQ ₆₀
19	DQ ₁₄	47	DQMB ₃	75	DQ29	103	DQ ₄₆	131	DQMB ₇	159	DQ ₆₁
20	DQ ₁₅	48	N.C.	76	DQ ₃₀	104	DQ ₄₇	132	N.C.	160	DQ ₆₂
21	N.C.	49	Vcc	77	DQ ₃₁	105	N.C.	133	Vcc	161	DQ ₆₃
22	N.C.	50	N.C.	78	Vss	106	N.C.	134	N.C.	162	Vss
23	Vss	51	N.C.	79	N.C.	107	Vss	135	N.C.	163	N.C.
24	N.C.	52	N.C.	80	N.C.	108	N.C.	136	N.C.	164	N.C.
25	N.C.	53	N.C.	81	N.C.	109	N.C.	137	N.C.	165	SA ₀
26	Vcc	54	Vss	82	SDA	110	Vcc	138	Vss	166	SA ₁
27	WE	55	DQ ₁₆	83	SCL	111	CAS	139	DQ ₄₈	167	SA ₂
28	DQMB ₀	56	DQ ₁₇	84	Vcc	112	DQMB ₄	140	DQ ₄₉	168	Vcc



■ PIN DESCRIPTIONS

Symbol	1/0	Function	Symbol	I/O	Function
A ₀ to A ₁₁	ı	Address Input	DQ ₀ to DQ ₆₃	I/O	Data Input/Data Output
RAS	ı	Row Address Strobe	Vcc	_	Power Supply (+3.3 V)
CAS	ı	Column Address Strobe	Vss	_	Ground (0 V)
WE	I	Write Enable	N.C.	_	No Connection
DQMB ₀ to DQMB ₇	ı	Data (DQ) Mask	SA ₀ to SA ₂	I	Serial PD Address Input
CLK ₀ , CLK ₁	I	Clock Input	SCL	I	Serial PD Clock
CKE	I	Clock Enable	SDA	I/O	Serial PD Address/Data Input/Output
CS₀ to CS₃	ı	Chip Select			

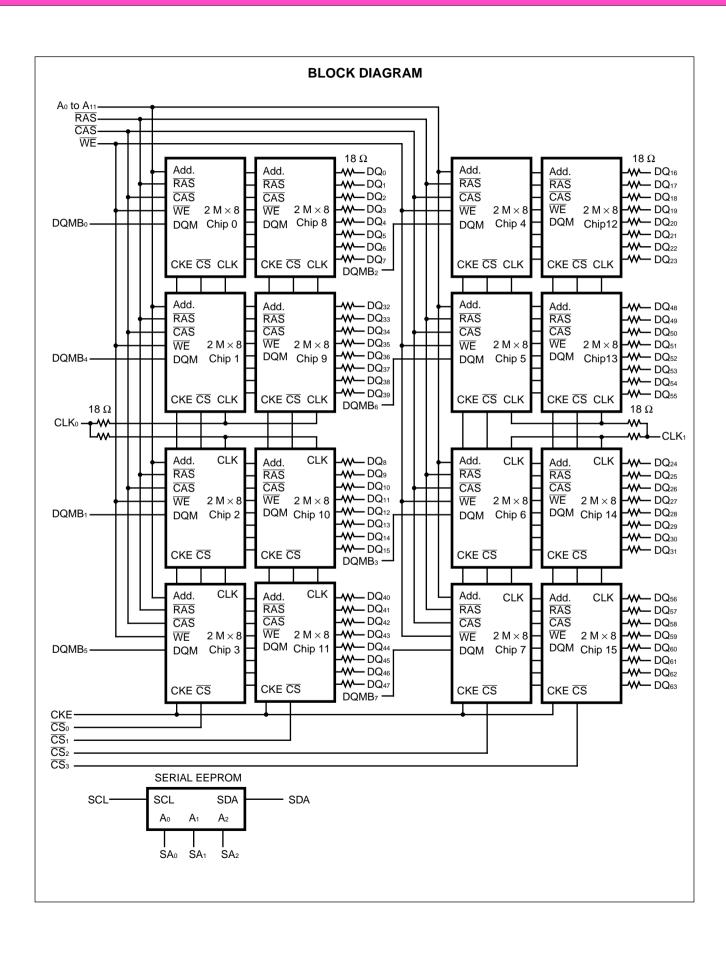
■ SERIAL-PD INFORMATION

Byte	Function Described		Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
0	Defines Number of Bytes Written into	128 Byte	1	0	0	0	0	0	0	0
	Serial Memory at Module Manufacture	•								
1	Total Number of Bytes of SPD Memory	256 Byte	0	0	0	0	1	0	0	0
2	Fundamental Memory Type	SDRAM	0	0	0	0	0	1	0	0
3	Number of Row Addresses	11	0	0	0	0	1	0	1	1
4	Number of Column Addresses	9	0	0	0	0	1	0	0	1
5	Number of Module Banks	2 bank	0	0	0	0	0	0	1	0
6	Data Width	64 bit	0	1	0	0	0	0	0	0
7	Data Width (Continuation)	+0	0	0	0	0	0	0	0	0
8	Interface Type	LVTTL	0	0	0	0	0	0	0	1
9	SDRAM Cycle Time	10 ns	1	0	1	0	0	0	0	0
		12 ns	1	1	0	0	0	0	0	0
		15 ns	1	1	1	1	0	0	0	0
10	SDRAM Access from Clock	8.5 ns	1	0	0	0	0	1	0	1
		9 ns	1	0	0	1	0	0	0	0
11	DIMM Configuration Type	Non-Parity	0	0	0	0	0	0	0	0
12	Refresh Rate/Type	Self, Norm	1	0	0	0	0	0	0	0
13	SDRAM Module Attributes	UN-Buffer	0	0	0	0	0	0	0	0
14	SDRAM Device Attributes	(*)	0	0	0	0	0	1	1	0
15	Minimum Clock Delay Back to Back	1 Cycle	0	0	0	0	0	0	0	1
	Random Column Address									
16	Burst Lengths Supported	1, 2, 4, 8	0	0	0	0	1	1	1	1
17	Number of Banks on Each SDRAM Device	2 bank	0	0	0	0	0	0	1	0
18	CAS Latency	2, 3	0	0	0	0	0	1	1	0
19	CS Latency	0	0	0	0	0	0	0	0	1
20	Write Latency	0	0	0	0	0	0	0	0	1
21 to 31	Reserved for Future Offerings	_	0	0	0	0	0	0	0	0
32 to 63	Superset Information	_	0	0	0	0	0	0	0	0
64 to 125		_	0	0	0	0	0	0	0	0
126	Intel Specification Frequency	66 MHz	0	1	1	0	0	1	1	0
127	Intel Specification CAS Latency	2, 3	0	0	0	0	0	1	1	0
128+	Unused Storage Locations	_	_	_	_	_	_	_	_	_

Note: Any write operation must NOT be executed into the addresses of Byte 0 to Byte 127. Some or all data stored into Byte 0 to Byte 127 may be broken.

(*) Byte 14: SDRAM Device Attributes

Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
TBD	TBD	TBD	TBD	Supported Single Write/ Burst Read	Supported Precharge All	Supported Auto- Precharge	Supported Early RAS Precharge
0	0	0	0	0	1	1	0



■ ABSOLUTE MAXIMUM RATINGS (See WARNING)

Parameter	Symbol	Va	lue	Unit
Faranietei	Symbol	Min.	Max.	Offic
Supply Voltage*	Vcc	-0.5	+4.6	V
Input Voltage*	Vin	-0.5	+4.6	V
Output Voltage*	Vouт	-0.5	+4.6	V
Storage Temperature	Тѕтс	– 55	+125	°C
Power Dissipation	P _D	_	10.2	W
Output Current (D.C.)	Іоит	-50	+50	mA

^{*:} Voltages referenced to Vss (= 0 V)

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

■ RECOMMENDED OPERATING CONDITIONS

Parameter	Notes	Symbol			Unit	
Farameter	Notes	Зуньы	Min.	Тур.	Max.	Offic
Cupply Voltage	*1	Vcc	3.0	3.3	3.6	V
Supply Voltage	I	Vss	0	0	0	V
Input High Voltage, all inputs	*1	ViH	2.0	_	Vcc +0.5	V
Input Low Voltage, all inputs	*1, 2	VIL	-0.5	_	0.8	V
Ambient Temperature		TA	0	_	+70	°C

^{*1.} Voltages referenced to Vss (= 0 V)

WARNING: Recommended operating conditions are normal operating ranges for the semiconductor device. All the device's electrical characteristics are warranted when operated within these ranges.

Always use semiconductor devices within the recommended operating conditions. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses , operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representative beforehand.

^{*2.} V_{\parallel} (min) = -1.5 V AC (Pulse Width \leq 5 ns)

■ CAPACITANCE

 $(Vcc = +3.3 \text{ V}, f = 1 \text{ MHz}, T_A = +25^{\circ}\text{C})$

Paramet	or	Symbol	Va	lue	Unit
raiaillei	CI	Syllibol	Min.	Max.	
	A ₀ to A ₁₁	C _{IN1}	_	72	pF
	RAS, CAS, WE	C _{IN2}	_	68	pF
	CS ₀ , CS ₃	Сімз	_	24	pF
Input Canacitanas	CKE	C _{IN4}	_	73	pF
Input Capacitance	CLK ₀ , CLK ₁	C _{IN5}	_	42	pF
	DQMB ₀ to DQMB ₇	C _{IN6}	_	17	pF
	SCL	Cscl	_	6	pF
	SA ₀ , SA ₁ , SA ₂	Csa	_	6	pF
Input/Output Capacitones	SDA	CSDA	_	7	pF
Input/Output Capacitance	DQ ₀ to DQ ₆₃	CDQ	_	21	pF

■ DC CHARACTERISTICS

(At recommended operating conditions unless otherwise noted.)

Doromotor	lotes		Symbol	Condition	Va	lue	Unit
Parameter N	iotes		Symbol	Condition	Min.	Max.	Unit
		MB8504S064AC-100		No Burst;		920	mA
		MB8504S064AC-84	Icc1s	tck = min	_	880	mA
Operating Current	*2	MB8504S064AC-67		One Bank Active		840	mA
(Average Power Supply Current)	2	MB8504S064AC-100		No Burst;		1280	mA
,		MB8504S064AC-84	Icc1D	tck = min trc = min	_	1200	mA
		MB8504S064AC-67		All Banks Active		1120	mA
Precharge Standby Current (Power			Ісс2Р	CKE = V _{IL} , t _{CK} = min All Banks Idle	_	32	mA
Supply Current)	*2		Icc2N	CKE = V _{IH} , tcк = min All Banks Idle	_	480	mA
Active Standby Current			Іссзр	CKE = V _{IL} , tck = min Any Bank Active	_	480	mA
(Power Supply Current)	*2		Іссзи	CKE = V _{IH} , t _{CK} = min Any Bank Active	_	640	mA
Burst Mode Current		MB8504S064AC-100			_	1320	mA
(Average Power	*2	MB8504S064AC-84	Icc4	tcк = min	_	1240	mA
Supply Current)		MB8504S064AC-67			_	1160	mA
Auto-refresh Current		MB8504S064AC-100		Auto Refresh	_	1360	mA
(Average Power	*2	MB8504S064AC-84	Icc5	tck = min trc = min	_	1280	mA
Supply Current)		MB8504S064AC-67		tred = min	_	1200	mA
Self-refresh Current (Average Power Supply C	Curren	nt)	Icc ₆	tck = VIL	_	32	mA
Input Leakage Current (A	All Inpu	uts)	lı (L)	$0 \text{ V} \le \text{V}_{\text{IN}} \le \text{V}_{\text{CC}}$ All other pins not under test = 0 V $3.0 \text{ V} \le \text{V}_{\text{CC}} \le 3.6 \text{ V}$	-80	80	μΑ
Output Leakage Current			I _{O(L)}	Output is disabled (Hi-Z) $0 \text{ V} \leq \text{Vout} \leq \text{Vcc}$ $3.0 \text{ V} \leq \text{Vcc} \leq 3.6 \text{ V}$	-20	20	μΑ
LVTTL Output High Voltage	*1		Vон	lон = −2.0 mA	2.4	_	V
LVTTL Output Low Voltage	*1		Vol	lo _L = +2.0 mA	_	0.4	V

- **Notes:** *1. Voltages referenced to Vss (= 0 V)
 - *2. lcc depends on the output termination, load conditions, clock cycle rate and signal clock rate. The specified values are obtained with the output open and no termination register.
 - *3. An initial pause (DESL on NOP) of 200 µs is required after power-on followed by a minimum of eight Auto-refresh cycles.
 - *4. Values except Icc2P are for when one side of the double-sided module is in standby mode and the other side has two banks active in burst mode.
 - *5. DC characteristics is the Serial PD standby state (V_{IN} = GND or V_{CC}).

■ AC CHARACTERISTICS

(1) BASE CHARACTERISTICS

(At recommended operating conditions unless otherwise noted.)

No.	Parameter Notes		Symbol		S064AC 00	MB8504 -8	S064AC 34		S064AC 67	Unit
			-	Min.	Max.	Min.	Max.	Min.	Max.	
1	Clock Period	CL = 3	tou	10	_	12	_	15	_	ns
'	Clock Period	CL = 2	tck -	15	_	17	_	20	_	ns
2	Clock High Time		tсн	4	_	4	_	4	_	ns
3	Clock Low Time		t cL	4	_	4	_	4	_	ns
4	CS Set Up Time		t sc	3	_	3	_	3	_	ns
5	CS Hold Time		t HC	1	_	1	_	1	_	ns
6	Input Set Up Time		t sı	3	_	3	_	3	_	ns
7	Input Hold Time		tнı	1	_	1		1	_	ns
8	Data Input Set Up Time		tsid	3	_	3	_	3	_	ns
9	Data Input Hold Time		t HID	1	_	1	_	1	_	ns
4.0	Output Valid	CL = 3	_	_	8.5		8.5		9	
10	from Clock *1, *2 (tclk = min)	CL = 2	t AC	_	9	_	9	_	10	ns
11	Output in Low-Z		tolz	3	_	3	_	3	_	ns
12	Output in High-Z *3		t onz	3	_	3	_	3	_	ns
13	Output Hold Time		tон	3	_	3	_	3	_	ns
14	Time between Refresh		t REF	_	32.8	_	32.8	_	32.8	ms
15	Transition Time		t⊤	0.5	2	0.5	2	0.5	2	ns
16	Power Down Exit Time		t PDE	3	_	4	_	5	_	ns

(2) BASE VALUES FOR CLOCK COUNT/LATENCY

No.	Parameter	Notes MB8504S064AC MB8504S064AC -100 -84				S064AC 57	Unit			
				Min.	Max.	Min.	Max.	Min	Max.	
1	RAS Cycle Time	*4	t RC	90	_	100	_	110	_	ns
2	RAS Access Time	*5	t RAC	_	54	_	56	_	60	ns
3	CAS Access Time	*6, *9	t cac		24	_	26		30	ns
4	RAS Precharge Time		t RP	30	_	35	_	40	_	ns
5	RAS Active Time		t RAS	60	100000	65	100000	70	100000	ns
6	RAS to CAS Delay Time	*7	t RCD	30	_	30	_	30	_	ns
7	Write Recovery Time		twr	10	_	12	_	15	_	ns
8	Write Precharge Time		t RWL	10	_	12	_	15	_	ns
9	RAS to CAS Bank Active Delay Time		t rrd	30	_	30	_	30	_	ns

(3) CLOCK COUNT FORMULA (*8)

$$Clock \ge \frac{Base\ Value}{Clock\ Period}$$
 (Round off a whole number)

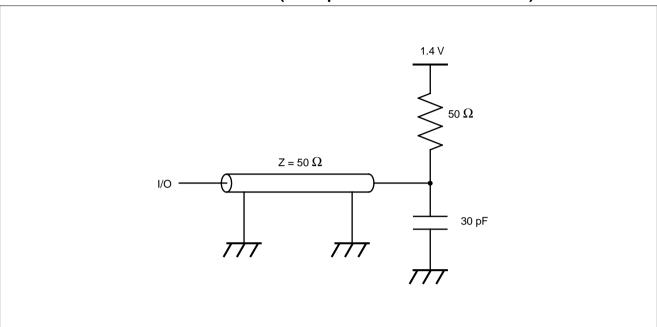
(4) LATENCY (The latency values on these parameters are fixed regardless of clock period.)

No.	Parameter		Symbol	MB8504S064AC -100	MB8504S064AC -84	MB8504S064AC -67	Unit
1	CKE to Clock Disable		Іске	1	1	1	Cycle
2	DQM to Output in High-Z		lpqz	2	2	2	Cycle
3	DQM to Input Data Delay	1	IDQD	0	0	0	Cycle
4	Last Output to Write Com Delay	nmand	lowd	2	2	2	Cycle
5	Write Command to Input Data Delay		lowo	0	0	0	Cycle
6	Precharge to	CL = 3	Ігон	3	3	3	Cycle
"	Output in High-Z Delay	CL = 2	IROH	2	2	2	Cycle
7	Mode Register Access to Bank Active (min)		I MRD	2	2	2	Cycle
8	CAS to CAS Delay (min)		Iccd	1	1	1	Cycle
9	CAS Bank Delay (min)		Ісво	1	1	1	Cycle

Notes: *1. Assumes trop and toac are satisfied.

- *2. tac also specifies the access time at burst mode except for first access.
- *3. Specified where output buffer is no longer driven.
- *4. Actual clock count of trc (Irc) will be sum of clock count of tras (Iras) and trp (Irp).
- *5. trac is a reference value. Maximum value is obtained from the sum of trcb (min) and tcac (max).
- *6. Assumes trac and tac are satisfied.
- *7. Operation within the trod (min) ensures that trac can be met; if trod is greater than the specified trod (min), access time is determined by toac and tac.
- *8. All base values are measured from the clock edge at the command input to the clock edge for the next command input.
 - All clock counts are calculated by a simple formula:
 - clock count equals base value divided by clock period (round off to a whole number).
- *9. The ICAC (CAS latency : CL) is programmed by the mode register.
- *10. An initial pause (DESL on NOP) of 200 μs is required after power-up followed by a minimum of eight Auto-refresh cycles.
- *11. 1.4 V or V_{REF} is the reference level for measuring timing of signals. Transition times are measured between V_{IH} (min) and V_{IL} (max).
- *12. AC characteristics assume $t_T = 1$ ns and 30 pF of capacitive load.
- *Source: See MB811171822A Data Sheet for details on the electricals.

■ AC OPERATING TEST CONDITION (Example of AC Test Load Circuit)



■ SERIAL PRESENCE DETECT (SPD) FUNCTION

1. PIN DESCRIPTIONS

SCL (Serial Clock)

SCL input is used to clock all data input/output of SPD

SDA (Serial Data)

SDA is a common pin used for all data input/output of SPD. The SDA pull-up resistor is required due to the open-drain output.

SA₀, SA₁, SA₂ (Address)

Address inputs are used to set the least significant three bits of the eight bits slave address. The address inputs must be fixed to select a particular module and the fixed address of each module must be different each other.

2. SPD OPERATIONS

CLOCK and DATA CONVENTION

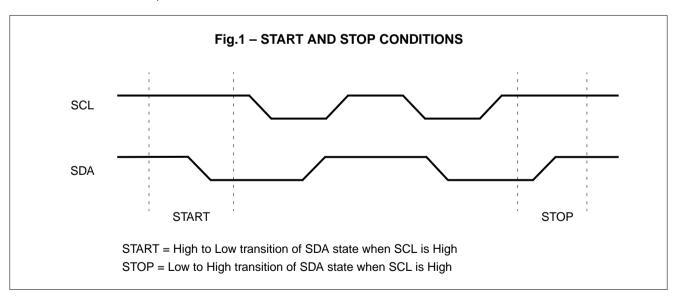
Data states on the SDA can change only during SCL=Low. SDA state changes during SCL=High are indicated start and stop conditions. Refer to Fig.1 below.

START CONDITION

All commands are preceded by a start condition, which is a transition of SDA state from High to Low when SCL=High. SPD will not respond to any command until this condition has been met.

STOP CONDITION

All read or write operation must be terminated by a stop condition, which is a transition of SDA state from Low to High when SCL=High. The stop condition is also used to make the SPD into the state of standby power mode after a read sequence.



ACKNOWLEDGE

Acknowledge is a software convention used to indicate successful data transfer. The transmitting device, either master or slave, will release the bus after transmitting eight bits. During the ninth clock cycle the receiver will put the SDA line to Low in order to acknowledge that it received the eight bits of data.

The SPD will respond with an acknowledge when it received the start condition followed by slave address issued by master.

In the read operation, the SPD will transmit eight bits of data, release the SDA line and monitor the line for an acknowledge. If an acknowledge is detected and no stop condition is issued by master, the SPD will continue to transmit data. If an acknowledge is not detected, the SPD will terminated further data transmissions. The master must then issue a stop condition to return the SPD to the standby power mode.

In the write operation, upon receipt of eight bits of data the SPD will respond with an acknowledge, and await the next eight bits of data, again responding with an acknowledge until the stop condition is issued by master.

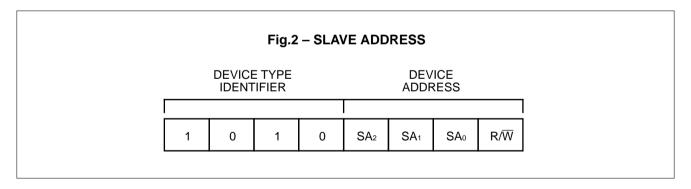
SLAVE ADDRESS ADDRESSING

Following a start condition, the master must output the eight bits slave address. The most significant four bits of the slave address are device type identifier. For the SPD this is fixed as 1010[B]. Refer to the Fig.2 below.

The next three significant bits are used to select a particular device. A system could have up to eight SPD devices—namely up to eight modules—on the bus. The eight addresses for eight SPD devices are defined by the state of the SA0, SA1 and SA2 inputs.

The last bit of the slave address defines the operation to be performed. When R/\overline{W} bit is "1", a read operation is selected, when R/\overline{W} bit is "0", a write operation is selected.

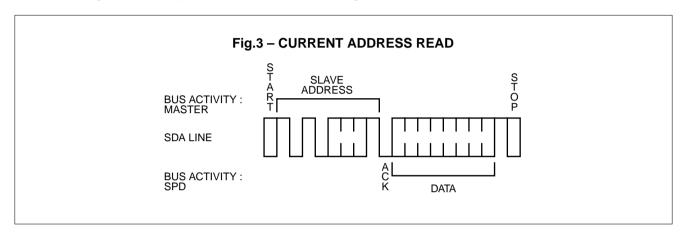
Following the start condition, the SPD monitors the SDA line comparing the slave address being transmitted with its slave address (device type and state of SA_0 , SA_1 , and SA_2 inputs). Upon a correct compare the SPD outputs an acknowledge on the SDA line. Depending on the state of the R/\overline{W} bit, the SPD will execute a read or write operation.



3. READ OPERATIONS

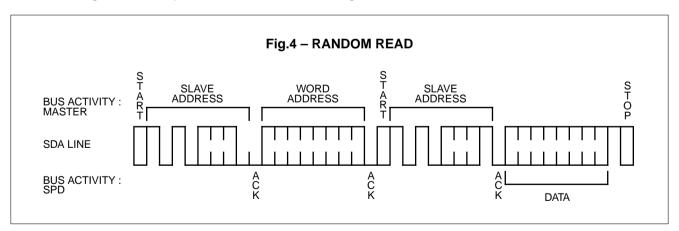
CURRENT ADDRESS READ

Internally the SPD contains an address counter that maintains the address of the last data accessed, incremented by one. Therefore, if the last access (either a read or write operation) was to address(n), the next read operation would access data from address(n+1). Upon receipt of the slave address with the R/\overline{W} bit = "1", the SPD issues an acknowledge and transmits the eight bits of data during the next eight clock cycles. The master terminates this transmission by issuing a stop condition, omitting the ninth clock cycle acknowledge. Refer to Fig.3 for the sequence of address, acknowledge and data transfer.



RANDOM READ

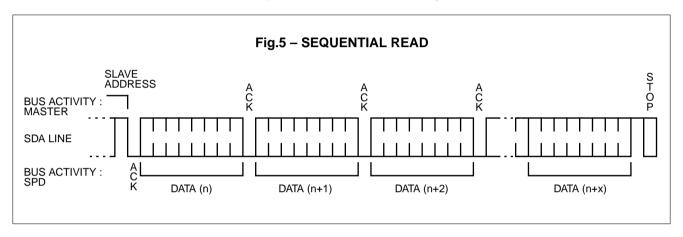
Random Read operations allow the master to access any memory location in a random manner. Prior to issuing the slave address with the R/\overline{W} bit = "1", the master must first perform a "dummy" write operation on the SPD. The master issues the start condition, and the slave address followed by the word address. After the word address acknowledge, the master immediately reissues the start condition and the slave address with the R/\overline{W} bit = "1". This will be followed by an acknowledge from the SPD and then by the eight bits of data. The master terminates this transmission by issuing a stop condition, omitting the ninth clock cycle acknowledge. Refer to Fig.4 for the sequence of address, acknowledge and data transfer.



SEQUENTIAL READ

Sequential Read can be initiated as either a current address read or random read. The first data are transmitted as with the other read mode, however, the master now responds with an acknowledge, indicating it requires additional data. The SPD continues to output data for each acknowledge received. The master terminates this transmission by issuing a stop condition, omitting the ninth clock cycle acknowledge. Refer to Fig.5 for the sequence of address, acknowledge and data transfer.

The data output is sequential, with the data from address(n) followed by the data from address(n+1). The address counter for read operations increments all address bits, allowing the entire memory contents to be serially read during one operation. At the end of the address space (address 255), the counter "rolls over" to address 0 and the SPD continues to output data for each acknowledge received.



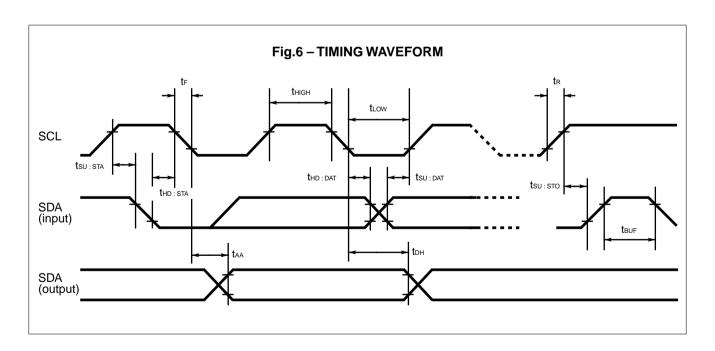
4. DC CHARACTERISTICS

Parameter	Note	Symbol	Condition	Value		Unit
				Min.	Max.	Oille
Input Leakage Current		Sili	0 V ≤ V _{IN} ≤ V _{CC}	-10	10	μΑ
Output Leakage Current		Silo	0 V ≤ Vouт ≤ Vcc	-10	10	μΑ
Output Low Voltage	*1	Svol	IoL = 3.0 mA	_	0.4	V

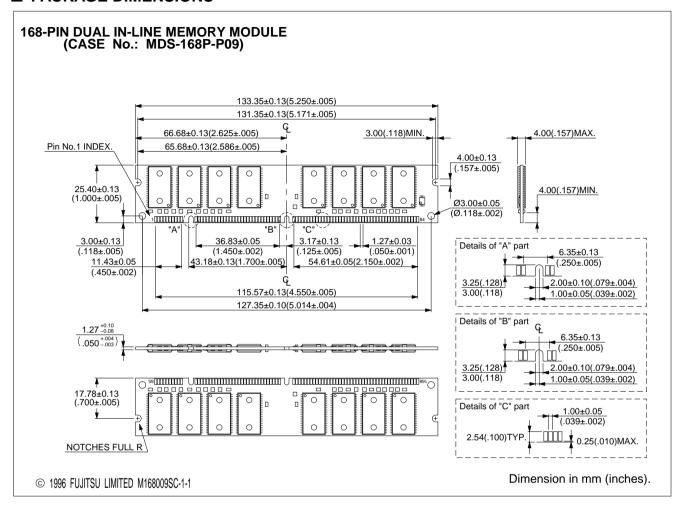
Note: *1. Referenced to Vss.

5. AC CHARACTERISTICS

No.	Parameter	Symbol	Min.	Max.	Unit
1	SCL Clock Frequency	fscL	0	100	KHz
2	Noise Suppression Time Constant at SCL, SDA Inputs	Tı	_	100	ns
3	SCL Low to SDA Data Out Valid	t AA	_	3.5	μs
4	Time the Bus Must Be Free Before a New Transmission Can Start	t BUF	4.7	_	μs
5	Start Condition Hold Time	thd:sta	4.0	_	μs
6	Clock Low Period	tLOW	4.7	_	μs
7	Clock High Period	t HIGH	4.0	_	μs
8	Start Condition Set Up Time	tsu:sta	4.7	_	μs
9	Data In Hold Time	thd:dat	0	_	μs
10	Data In Set Up Time	tsu:dat	250	_	ns
11	SDA and SCL Rise Time	t R	_	1	μs
12	SDA and SCL Fall Time	t⊧	_	300	ns
13	Stop Condition Set Up Time	t su:sто	4.7	_	μs
14	Data Out Hold Time	t DH	100	_	ns
15	Write Cycle Time	t wr	_	15	ms



■ PACKAGE DIMENSIONS



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